TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSIII)

2SK2608

Switching Regulator Applications

• Low drain-source ON resistance : $RDS(ON) = 3.73 \Omega \text{ (typ.)}$

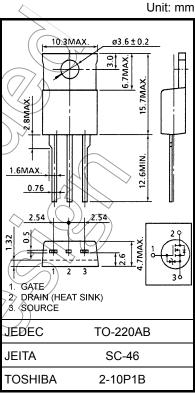
• High forward transfer admittance $|Y_{fs}| = 2.6 S \text{ (typ.)}$

• Low leakage current $I_{DSS} = 100 \,\mu\text{A} \,(\text{max}) \,(V_{DS} = 720 \,\text{V})$

• Enhancement mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

				< . /
Characteris	stics	Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	900	(v)
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	900	V
Gate-source voltage		V_{GSS}	±30	V
Drain current	DC (Note 1)	I _D	3	~ A
	Pulse (Note 1)	I _{DP}	9	Α
Drain power dissipation	n (Tc = 25°C)	PD	100	W
Single pulse avalanche	e energy (Note 2)	EAS	295	mJ
Avalanche current		I _{AR})) 3	Α
Repetitive avalanche e	nergy (Note 3)	EAR	10.0	mJ
Channel temperature		(T _{ch})	150	Ĵ¢¢
Storage temperature ra	ange	Tstg	-55 to 150	\~c
	_	/ /		_



Weight: 2.0 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics Symbol	Max	Unit
Thermal resistance, channel to case Rth (ch-c)	1.25	°C/W
Thermal resistance, channel to ambient Rth (ch-a)	83.3	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 60.0 mH, R_G = 25 Ω , I_{AR} = 3 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

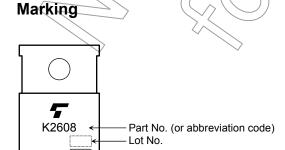
Please handle with caution.

Electrical Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±30 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 720 V, V _{GS} = 0 V		_	100	μA
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	900	_	_	V
Gate threshold v	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) >-	4.0	V
Drain-source O	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 1.5 A	\nearrow	3.73	4.3	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 20 V, I _D = 1.5 A	0.65	2.6	_	S
Input capacitano	е	C _{iss}		_	750	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	10	_	pF
Output capacita	nce	Coss		_	70		
Switching time	Rise time	t _r	V_{GS}^{10V} V_{GS}^{10V} $R_{L}=133\Omega$	- (15	\(\sigma\) \(\sigma\)	
	Turn-on time	t _{on}			55) –	
	Fall time	t _f		7	30	_	ns
	Turn-off time	t _{off}	$V_{DD} = 200V$ Duty 1%, $t_{W} = 10 \mu s$) -	110	_	
Total gate charg plus gate-drain)		Qg			25		
Gate-source charge Q _{gs}		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, D = 3 \text{ A}$	_	13		nC
Gate-drain ("miller") Charge Q _{gd}		Q _{gd}		_	12	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	3	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	ı	_	9	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 3 A, V _{GS} = 0 V		_	-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 3 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / μs		1200	_	ns
Reverse recovery charge	Q _{rr}	10R - 3 A, VGS - 0 V, αιDR / αι - 100 A / μs	1	8.5		μC



Note 4

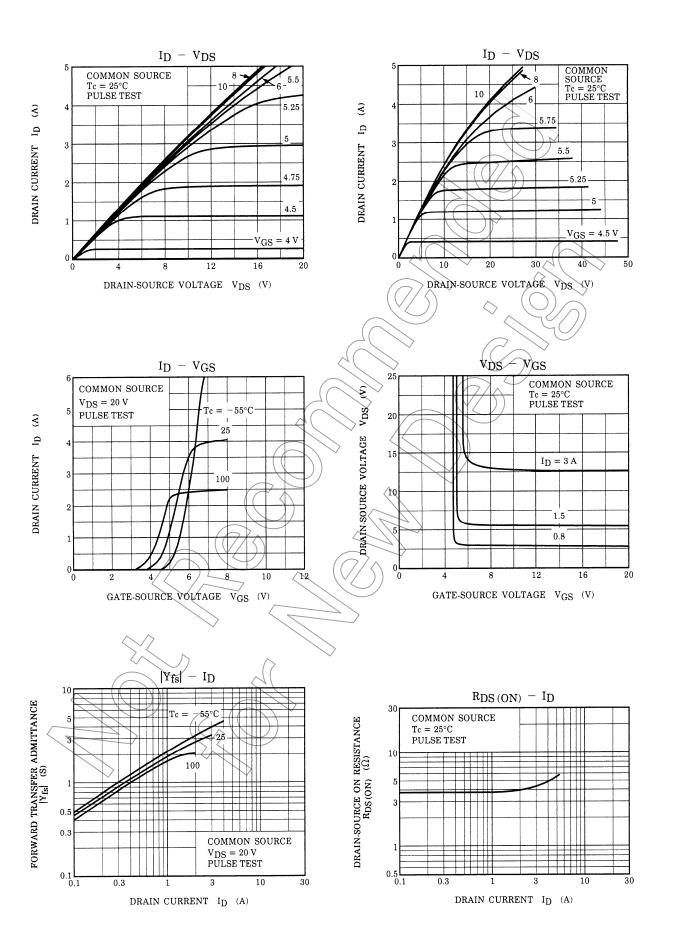
Note 4: A line under a Lot No. identifies the indication of product labels

Not underlined: [[Pb]]/INCLUDES > MCV

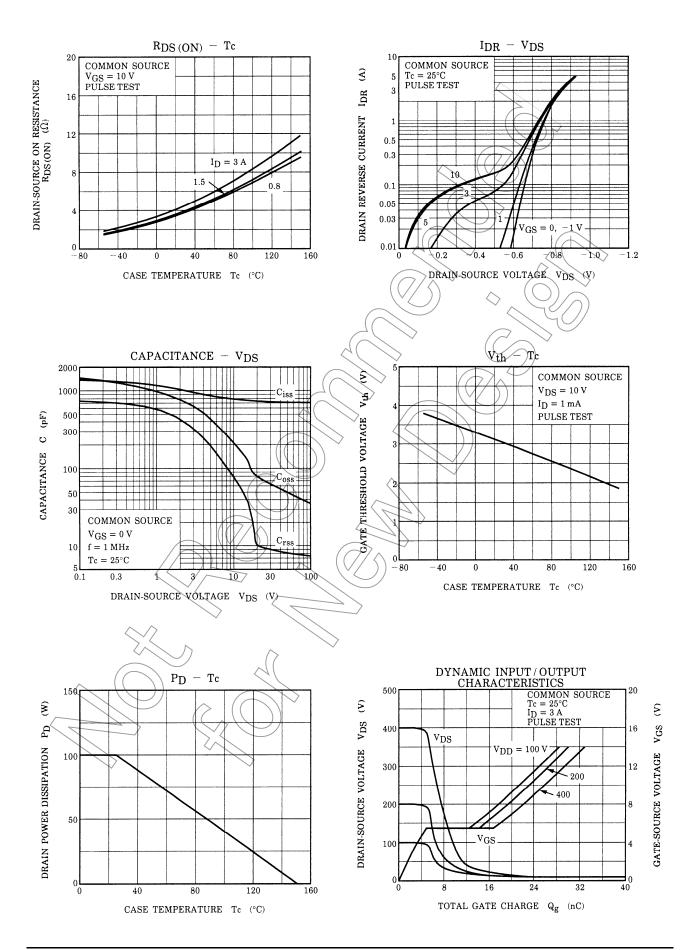
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

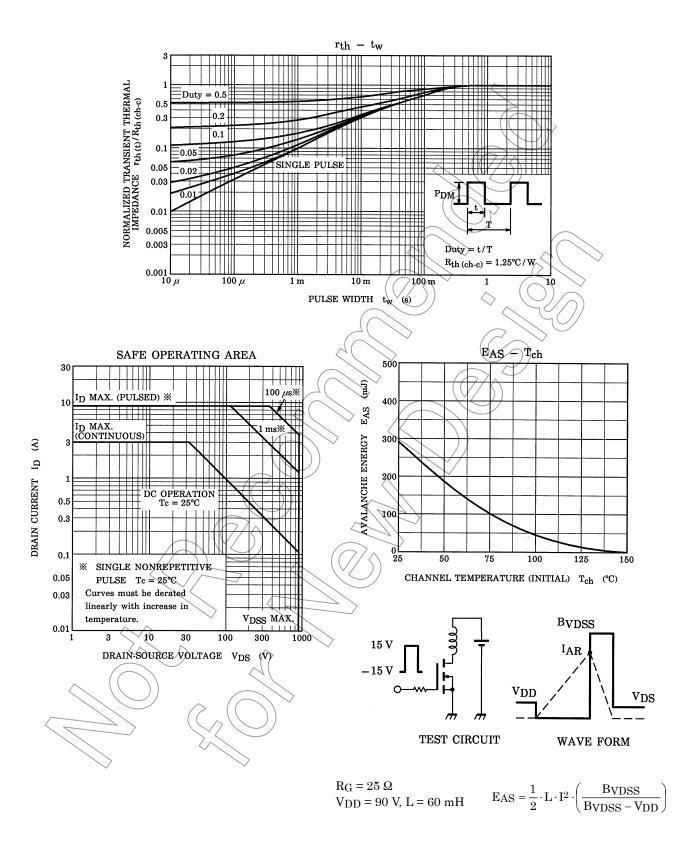
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